

FZT589

30V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- BVceo > -30V
- Ic = -1A High Continuous Current
- Excellent here Characteristics up to -2A
- Low Saturation Voltage V_{CE(sat)} < -0.35V @ -1A
- Complementary NPN Type: FZT489
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

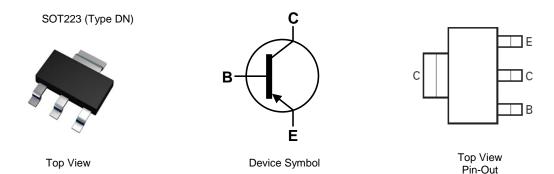
https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)



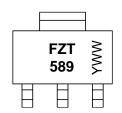
Ordering Information (Note 4)

Part Number	Dookogo	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
Part Number	Package	Warking	Reel Size (Iliches)	rape widin (min)	Qty.	Carrier
FZT589TA	SOT223 (Type DN)	FZT589	7	12	1,000	Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



FZT 589 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 2 = 2022) WW or $\overline{W}W$ = Week Code (01 to 53)



Absolute Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	-50	V
Collector-Emitter Voltage	Vceo	-30	V
Emitter-Base Voltage	VEBO	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	Ісм	-2	Α

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Dower Discipation	(Note 5)	D-	2	W
Power Dissipation	(Note 6)	PD	3	W
Thermal Decistores Junction to Ambient	(Note 5)	Devi	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 3	Røjl	19.4	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

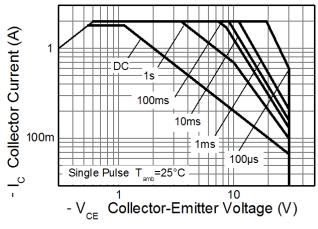
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

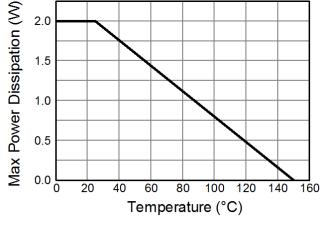
Notes:

- 5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 50mm x 50mm single sided 2oz weight copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

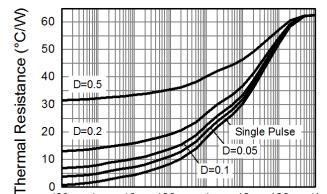


Thermal Characteristics and Derating Information

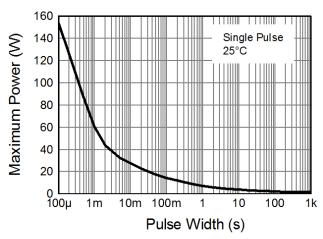




Safe Operating Area



Derating Curve



Pulse Width (s) **Transient Thermal Impedance**

10

100

1k

100m

10m

Pulse Power Dissipation



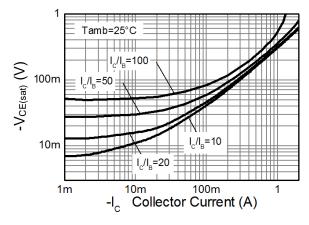
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-50	_	_	V	Ic = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BVCEO	-30	_	_	V	Ic = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	_	_	V	IE = -100μA
Collector Cut-Off Current	Ісво	_	_	-100	nA	V _{CB} = -30V
Collector Emitter Cut-Off Current	Ices	_	_	-100	nA	Vces = -30V
Emitter Cut-Off Current	I _{EBO}	_	_	-100	nA	V _{EB} = -4V
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)	_	_	-0.35 -0.65	V	I _C = -1A, I _B = -100mA I _C = -2A, I _B = -200mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE} (sat)	_	_	-1.2	V	Ic = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	_	-1.1	V	Ic = -1A, VcE = -2V
DC Current Transfer Static Ratio (Note 9)	hFE	100 100 80 40	_ _ _	300 — —	_ _ _ _	Ic = -1mA, VcE = -2V Ic = -500mA, VcE = -2V Ic = -1A, VcE = -2V Ic = -2A, VcE = -2V
Transitional Frequency (Note 9)	f⊤	100	_	_	MHz	V _{CE} = -5V, I _C = -100mA f = 100MHz
Output Capacitance (Note 9)	Cobo	_	_	15	pF	V _{CB} = -10V, f = 1MHz
Switching Times	t _{on}		50 300	_	ns	Ic = -500mA, Vcc = -10V I _{B1} = -I _{B2} = -50mA

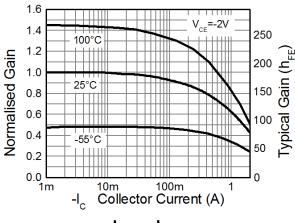
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



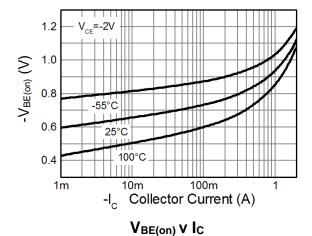
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

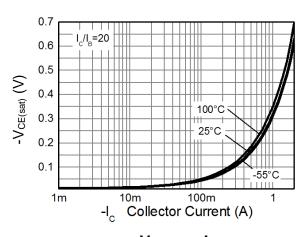


V_{CE(sat)} v I_C

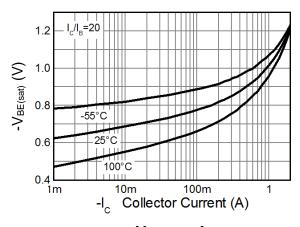


 $\mathbf{h}_{\mathrm{FE}} \, \mathbf{v} \, \, \mathbf{I}_{\mathrm{C}}$





 $V_{\text{CE(sat)}} v I_{\text{C}}$



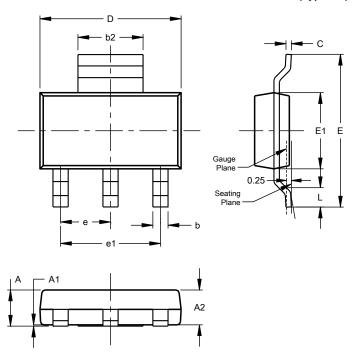
V_{BE(sat)} v I_C



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

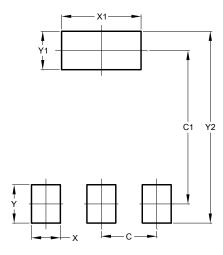


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
V2	8.00



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